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HMC365G8* Product Page Quick Links

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Quality Documentation

- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

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Typical Applications

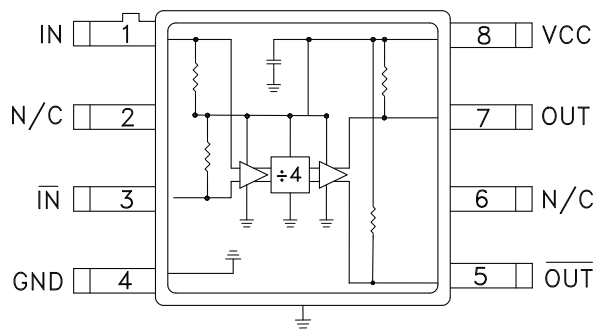
Prescaler for DC to Ku Band PLL Applications:

- Point-to-Point / Multi-Point Radios
- VSAT Radios
- Fiber Optic
- Test Equipment
- Space & Military

Features

- Ultra Low SSB Phase Noise: -151 dBc/Hz
- Wide Bandwidth
- Output Power: 7 dBm
- Single DC Supply: +5V
- 8 Lead Hermetic SMT Package

Functional Diagram



General Description

The HMC365G8 is a low noise Divide-by-4 Static Divider with InGaP GaAs HBT technology in an 8 lead glass/metal (hermetic) surface mount hermetic package. This device operates from DC (with a square wave input) to 13 GHz input frequency with a single +5V DC supply. The low additive SSB phase noise of -151 dBc/Hz at 100 kHz offset helps the user maintain good system noise performance.

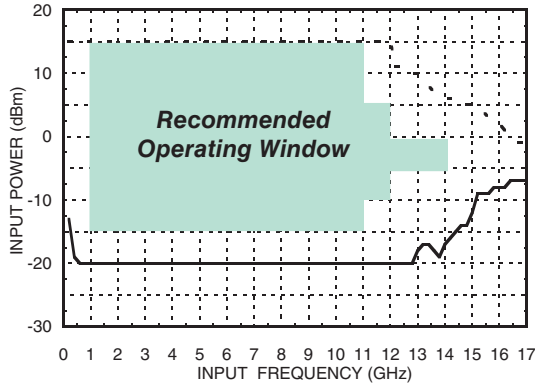
Electrical Specifications, $T_A = +25^\circ C$, 50 Ohm System, $V_{cc} = 5V$

Parameter	Conditions	Min.	Typ.	Max.	Units
Maximum Input Frequency		13	14		GHz
Minimum Input Frequency	Sine Wave Input. [1]		0.2	0.5	GHz
Input Power Range	$F_{in} = 1$ to 11 GHz	-15	>-20	+10	dBm
	$F_{in} = 11$ to 12 GHz	-10	>-15	+5	dBm
	$F_{in} = 12$ to 13 GHz	-5	>-8	0	dBm
Output Power	$F_{in} = 13$ GHz	3	7		dBm
Reverse Leakage	Both RF Outputs Terminated		45		dB
SSB Phase Noise (100 kHz offset)	$P_{in} = 0$ dBm, $F_{in} = 6$ GHz		-151		dBc/Hz
Output Transition Time	$P_{in} = 0$ dBm, $F_{out} = 882$ MHz		100		ps
Supply Current (I_{cc})			120		mA

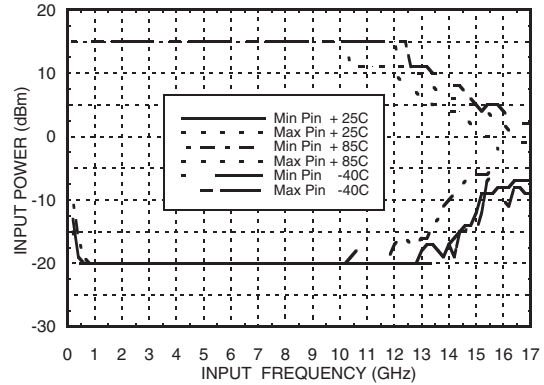
1. Divider will operate down to DC for square-wave input signal.

**SMT GaAs HBT MMIC
DIVIDE-BY-4, DC - 13 GHz**

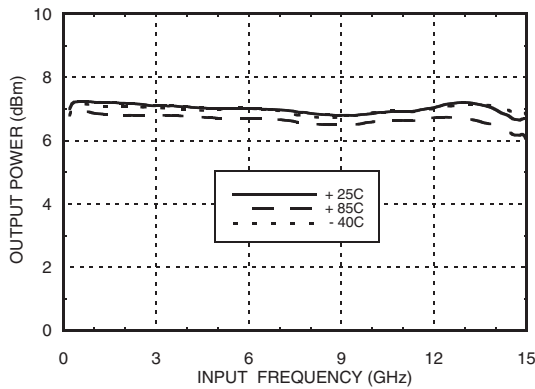
Input Sensitivity Window, $T = 25\text{ }^{\circ}\text{C}$



Input Sensitivity Window vs. Temperature

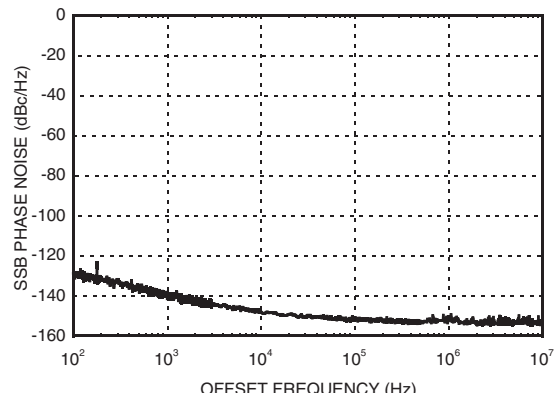


Output Power vs. Temperature



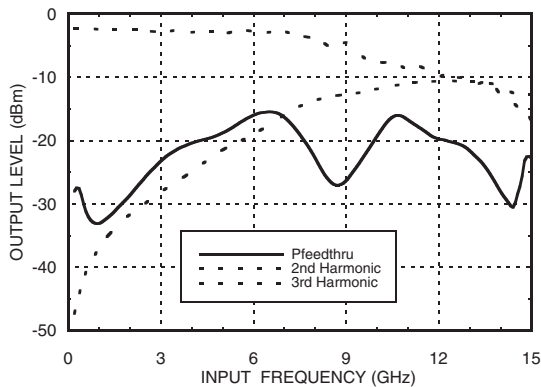
SSB Phase Noise

Performance, $P_{in} = 0\text{ dBm}$, $T = 25\text{ }^{\circ}\text{C}$

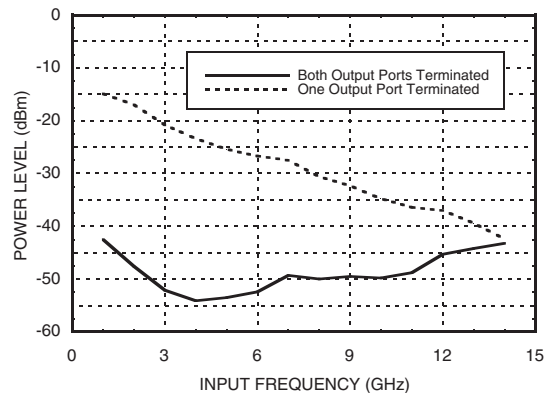


Output Harmonic

Content, $P_{in} = 0\text{ dBm}$, $T = 25\text{ }^{\circ}\text{C}$

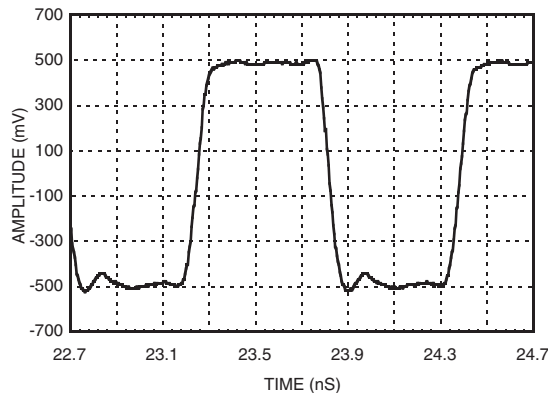


Reverse Leakage, $P_{in} = 0\text{ dBm}$, $T = 25\text{ }^{\circ}\text{C}$



**SMT GaAs HBT MMIC
DIVIDE-BY-4, DC - 13 GHz**

**Output Voltage Waveform,
Pin= 0 dBm, Fout= 882 MHz, T= 25 °C**



Absolute Maximum Ratings

RF Input (Vcc = +5V)	+13 dBm
Vcc	+5.5V
Junction Temperature (T _j)	135 °C
Continuous P _{diss} (T = 85 °C) (derate 12.5 mW/°C above 85 °C)	625 mW
Thermal Resistance (R _{TH}) (junction to ground paddle)	80 °C/W
Storage Temperature	-65 to -150 °C
Operating Temperature	-40 to +85 °C

Typical Supply Current vs. Vcc

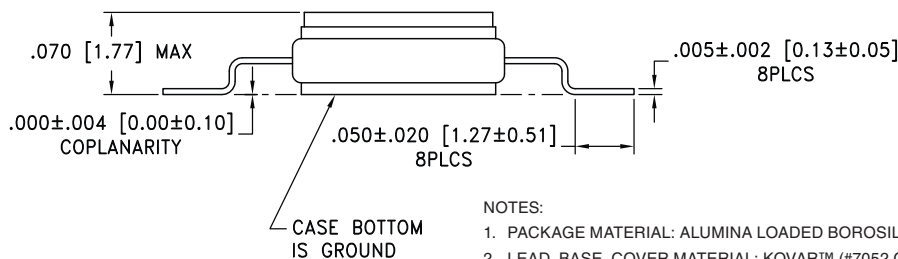
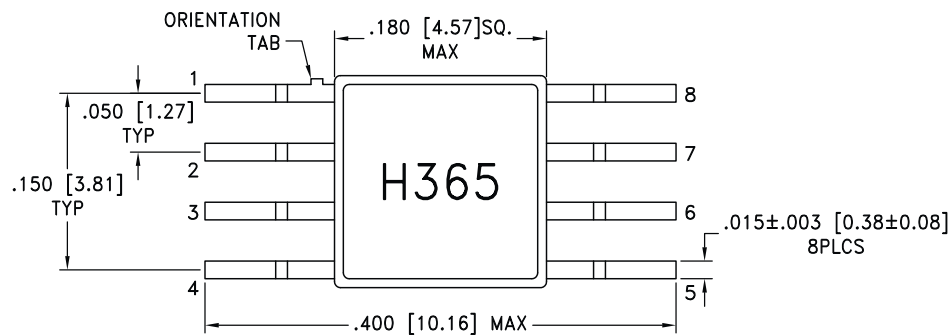
Vcc (V)	Icc (mA)
4.75	110
5.0	120
5.25	130

Note: Divider will operate over full voltage range shown above



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



NOTES:

1. PACKAGE MATERIAL: ALUMINA LOADED BOROSILICATE GLASS.
2. LEAD, BASE, COVER MATERIAL: KOVAR™ (#7052 CORNING).
3. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 50 MICROINCHES MIN.
4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
5. TOLERANCES: ±.005 [0.13] UNLESS OTHERWISE SPECIFIED.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

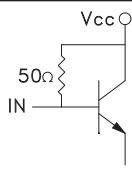
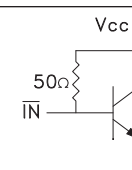

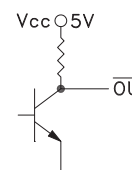
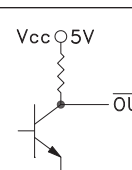
For price, delivery and to place orders: Hittite Microwave Corporation, 20 Alpha Road, Chelmsford, MA 01824

Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

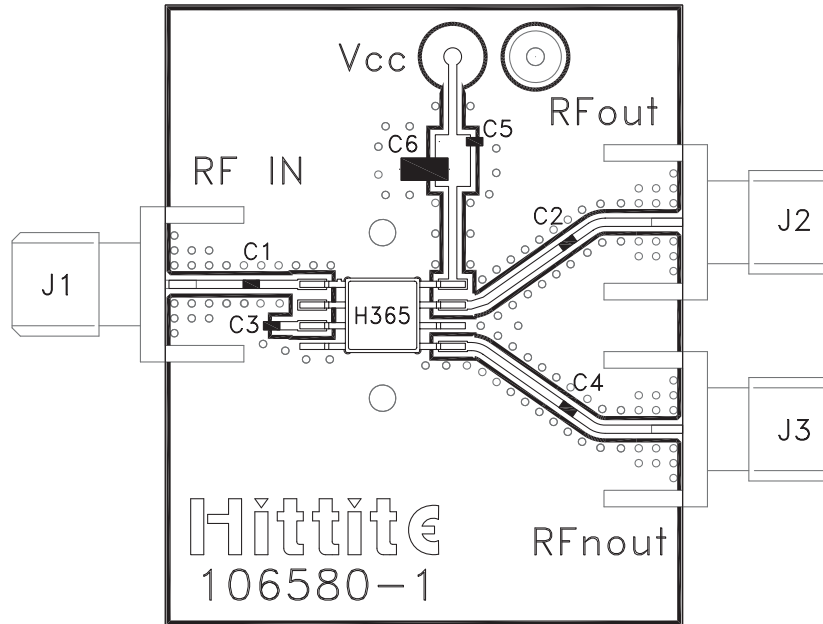
Application Support: Phone: 978-250-3343 or apps@hittite.com

**SMT GaAs HBT MMIC
DIVIDE-BY-4, DC - 13 GHz**

Pin Description

Pin Number	Function	Description	Interface Schematic
1	IN	RF Input must be DC blocked.	
2, 6	N/C	No connection.	
3	$\overline{\text{IN}}$	RF Input 180° out of phase with pin 1 for differential operation. AC ground for single ended operation.	
4	GND	Ground: Backside of package has exposed metal ground which must be connected to a RF/DC ground.	
5	$\overline{\text{OUT}}$	Divided output 180° out of phase with pin 7.	
7	OUT	Divided Output.	
8	VCC	Supply voltage 5V ± 0.25V.	

Evaluation PCB



List of Materials for Evaluation PCB 106582 [1]

Item	Description
J1 - J3	PCB Mount SMA RF Connector
C1 - C4	100 pF Capacitor, 0402 Pkg,
C5	1000 pF Capacitor, 0603 Pkg.
C6	10 μF Tantalum Capacitor
U1	HMC365G8 Divide-by-4
PCB [2]	106580 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and backside ground slug should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request. This evaluation board is designed for single ended input testing. J2 and J3 provide differential output signals.

**SMT GaAs HBT MMIC
DIVIDE-BY-4, DC - 13 GHz**

Application Circuit

